

DATA SHEET

74LVT16244B

3.3V LVT 16-bit buffer/driver (3-State)

Product specification
Supersedes data of 1998 Feb 19
IC23 Data Handbook

1998 Oct 07

3.3V 16-bit buffer/driver (3-State)

74LVT16244B

FEATURES

- 16-bit bus interface
- 3-State buffers
- Output capability: +64mA/-32mA
- TTL input and output switching levels
- Input and output interface capability to systems at 5V supply
- Bus-hold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power-up 3-State
- No bus current loading when output is tied to 5V bus
- Latch-up protection exceeds 500mA per JEDEC Std 17
- ESD protection exceeds 2000V per MIL STD 883 Method 3015 and 200V per Machine Model

DESCRIPTION

The 74LVT16244B is a high-performance BiCMOS product designed for V_{CC} operation at 3.3V.

This device is a 16-bit buffer and line driver featuring non-inverting 3-State bus outputs. The device can be used as four 4-bit buffers, two 8-bit buffers, or one 16-bit buffer.

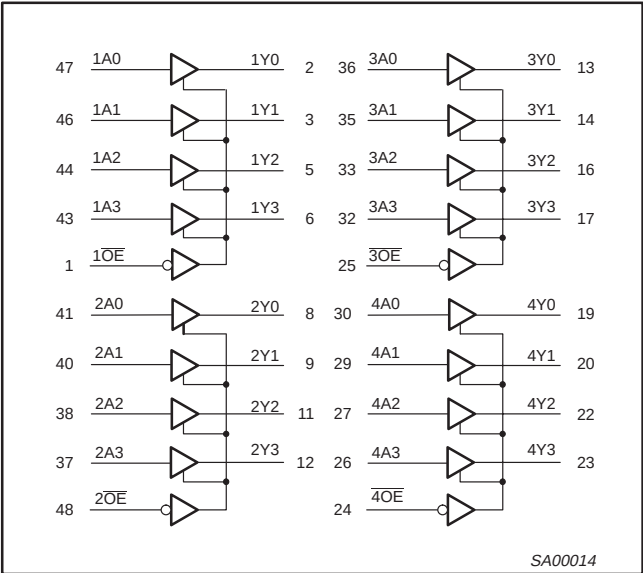
QUICK REFERENCE DATA

SYMBOL	PARAMETER	CONDITIONS $T_{amb} = 25^{\circ}C$	TYPICAL	UNIT
t_{PLH} t_{PHL}	Propagation delay nAx to nYx	$C_L = 50pF$; $V_{CC} = 3.3V$	1.8	ns
C_{IN}	Input capacitance nOE	$V_I = 0V$ or 3.0V	3	pF
C_{OUT}	Output capacitance	Outputs disabled; $V_O = 0V$ or 3.0V	9	pF
I_{CCZ}	Total supply current	Outputs disabled; $V_{CC} = 3.6V$	70	μA

ORDERING INFORMATION

PACKAGES	TEMPERATURE RANGE	OUTSIDE NORTH AMERICA	NORTH AMERICA	DWG NUMBER
48-Pin Plastic SSOP Type III	$-40^{\circ}C$ to $+85^{\circ}C$	74LVT16244B DL	VT16244B DL	SOT370-1
48-Pin Plastic TSSOP Type II	$-40^{\circ}C$ to $+85^{\circ}C$	74LVT16244B DGG	VT16244B DGG	SOT362-1

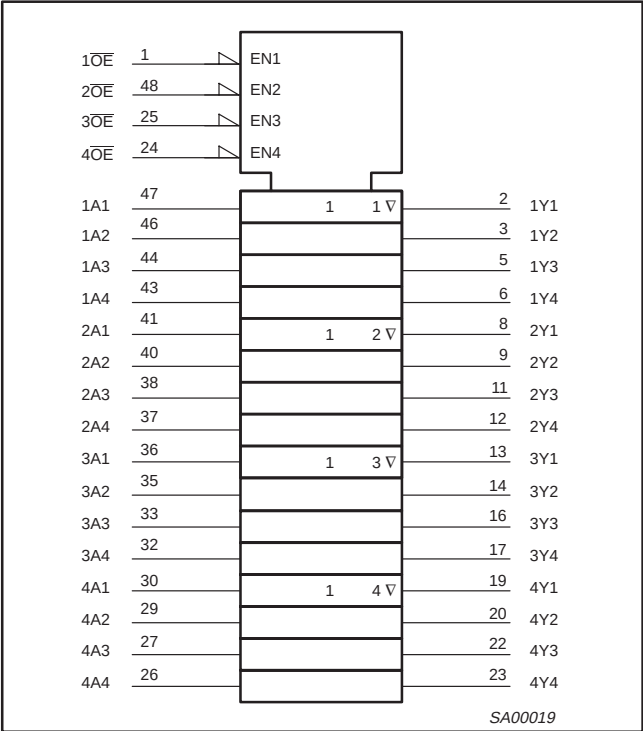
LOGIC SYMBOL



3.3V 16-bit buffer/driver (3-State)

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LOGIC SYMBOL (IEEE/IEC)



PIN DESCRIPTION

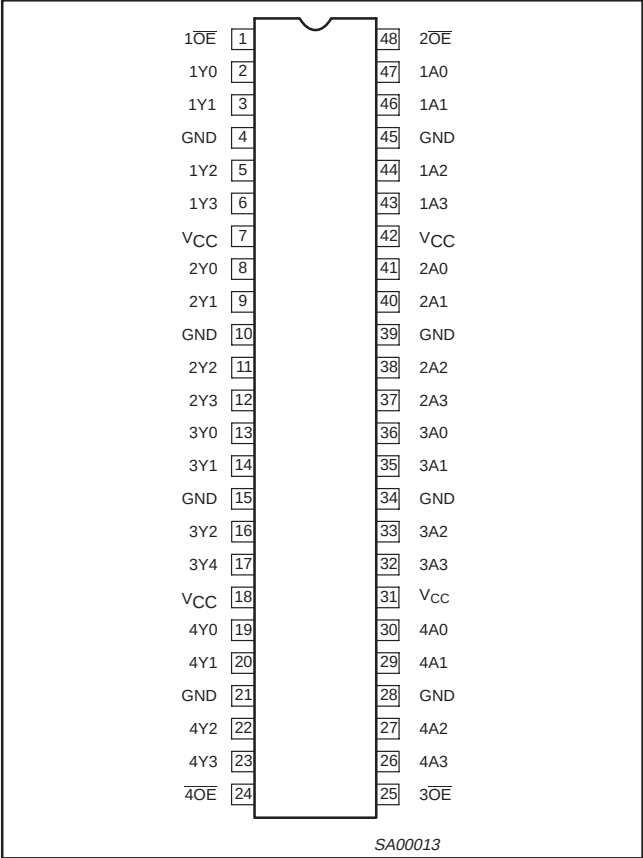
PIN NUMBER	SYMBOL	NAME AND FUNCTION
47, 46, 44, 43 41, 40, 38, 37 36, 35, 33, 32 30, 29, 27, 26	1A0 - 1A3, 2A0 - 2A3, 3A0 - 3A3, 4A0 - 4A3	Data inputs
2, 3, 5, 6 8, 9, 11, 12 13, 14, 16, 17 19, 20, 22, 23	1Y0 - 1Y3, 2Y0 - 2Y3, 3Y0 - 3Y3, 4Y0 - 4Y3	Data outputs
1, 48 25, 24	1OE, 2OE, 3OE, 4OE	Output enables
4, 10, 15, 21 28, 34, 39, 45	GND	Ground (0V)
7, 18, 31, 42	V _{CC}	Positive supply voltage

FUNCTION TABLE

INPUTS		OUTPUTS
nOE	nAx	nYx
L	L	L
L	H	H
H	X	Z

H = High voltage level
L = Low voltage level
X = Don't care
Z = High Impedance "off" state

PIN CONFIGURATION



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ABSOLUTE MAXIMUM RATINGS^{1, 2}

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V_{CC}	DC supply voltage		-0.5 to +4.6	V
I_{IK}	DC input diode current	$V_I < 0$	-50	mA
V_I	DC input voltage ³		-0.5 to +7.0	V
I_{OK}	DC output diode current	$V_O < 0$	-50	mA
V_{OUT}	DC output voltage ³	Output in Off or High state	-0.5 to +7.0	V
I_{OUT}	DC output current	Output in Low state	128	mA
		Output in High state	-64	
T_{stg}	Storage temperature range		-65 to +150	°C

NOTES:

1. Stresses beyond those listed may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
2. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability. The maximum junction temperature of this integrated circuit should not exceed 150°C.
3. The input and output negative voltage ratings may be exceeded if the input and output clamp current ratings are observed.

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMITS		UNIT
		MIN	MAX	
V_{CC}	DC supply voltage	2.7	3.6	V
V_I	Input voltage	0	5.5	V
V_{IH}	High-level input voltage	2.0		V
V_{IL}	Input voltage		0.8	V
I_{OH}	High-level output current		-32	mA
I_{OL}	Low-level output current		32	mA
	Low-level output current; current duty cycle $\leq 50\%$; $f \geq 1\text{kHz}$		64	
$\Delta t/\Delta v$	Input transition rise or fall rate; Outputs enabled		10	ns/V
T_{amb}	Operating free-air temperature range	-40	+85	°C

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DC ELECTRICAL CHARACTERISTICS

SYMBOL	PARAMETER	TEST CONDITIONS		LIMITS			UNIT
				Temp = -40°C to +85°C			
				MIN	TYP ¹	MAX	
V _{IK}	Input clamp voltage	V _{CC} = 2.7V; I _{IK} = -18mA			-0.85	-1.2	V
V _{OH}	High-level output voltage	V _{CC} = 2.7 to 3.6V; I _{OH} = -100μA		V _{CC} -0.2	V _{CC}		V
		V _{CC} = 2.7V; I _{OH} = -8mA		2.4	2.5		
		V _{CC} = 3.0V; I _{OH} = -32mA		2.0	2.3		
V _{OL}	Low-level output voltage	V _{CC} = 2.7V; I _{OL} = 100μA			0.07	0.2	V
		V _{CC} = 2.7V; I _{OL} = 24mA			0.3	0.5	
		V _{CC} = 3.0V; I _{OL} = 16mA			0.25	0.4	
		V _{CC} = 3.0V; I _{OL} = 32mA			0.3	0.5	
		V _{CC} = 3.0V; I _{OL} = 64mA			0.4	0.55	
I _I	Input leakage current	V _{CC} = 3.6V; V _I = V _{CC} or GND	Control pins		0.1	±1.0	μA
		V _{CC} = 0 or 3.6V; V _I = 5.5V			0.4	10	
		V _{CC} = 3.6V; V _I = V _{CC}	Data pins ⁴		0.1	1	
		V _{CC} = 3.6V; V _I = 0			-0.4	-5	
I _{OFF}	Output off current	V _{CC} = 0V; V _I or V _O = 0 to 4.5V			0.1	±100	μA
I _{HOLD}	Bus Hold current A inputs ⁶	V _{CC} = 3V; V _I = 0.8V		75	135		μA
		V _{CC} = 3V; V _I = 2.0V		-75	-135		
		V _{CC} = 0V to 3.6V; V _{CC} = 3.6V		±500			
I _{EX}	Current into an output in the High state when V _O > V _{CC}	V _O = 5.5V; V _{CC} = 3.0V			50	125	μA
I _{PU/PD}	Power up/down 3-State output current ³	V _{CC} ≤ 1.2V; V _O = 0.5V to V _{CC} ; V _I = GND or V _{CC} OE/OE = Don't care			1	±100	μA
I _{OZH}	3-State output High current	V _{CC} = 3.6V; V _O = 3.0V; V _I = V _{IL} or V _{IH}			0.5	5	μA
I _{OZL}	3-State output Low current	V _{CC} = 3.6V; V _O = 0.5V; V _I = V _{IL} or V _{IH}			0.5	-5	μA
I _{CCH}	Quiescent supply current	V _{CC} = 3.6V; Outputs High, V _I = GND or V _{CC} , I _O = 0			0.07	0.12	mA
I _{CCL}		V _{CC} = 3.6V; Outputs Low, V _I = GND or V _{CC} , I _O = 0			4.0	6.0	
I _{CCZ}		V _{CC} = 3.6V; Outputs Disabled; V _I = GND or V _{CC} , I _O = 0 ⁵			0.07	0.12	
ΔI _{CC}	Additional supply current per input pin ²	V _{CC} = 3V to 3.6V; One input at V _{CC} -0.6V, Other inputs at V _{CC} or GND			0.1	0.2	mA

NOTES:

1. All typical values are at $V_{CC} = 3.3V$ and $T_{amb} = 25^\circ C$.
2. This is the increase in supply current for each input at the specified voltage level other than V_{CC} or GND
3. This parameter is valid for any V_{CC} between 0V and 1.2V with a transition time of up to 10msec. From $V_{CC} = 1.2V$ to $V_{CC} = 3.3V \pm 0.3V$ a transition time of 100 μ sec is permitted. This parameter is valid for $T_{amb} = 25^\circ C$ only.
4. Unused pins at V_{CC} or GND.
5. I_{CCZ} is measured with outputs pulled to V_{CC} or GND.
6. This is the bus hold overdrive current required to force the input to the opposite logic state.

AC CHARACTERISTICS

GND = 0V; $t_R = t_F = 2.5ns$; $C_L = 50pF$; $R_L = 500\Omega$; $T_{amb} = -40^\circ C$ to $+85^\circ C$.

SYMBOL	PARAMETER	WAVEFORM	LIMITS				UNIT
			$V_{CC} = 3.3V \pm 0.3V$			$V_{CC} = 2.7V$	
			MIN	TYP ¹	MAX	MAX	
t_{PLH} t_{PHL}	Propagation delay nAx to nYx	1	0.5 0.5	1.8 1.7	3.2 3.2	4.0 4.0	ns
t_{PZH} t_{PZL}	Output enable time to High and Low level	2	1.0 1.0	2.3 2.1	4.0 4.0	5.0 5.3	ns
t_{PHZ} t_{PLZ}	Output disable time from High and Low Level	2	1.0 1.0	3.2 2.9	4.5 4.0	5.0 4.4	ns

NOTE:

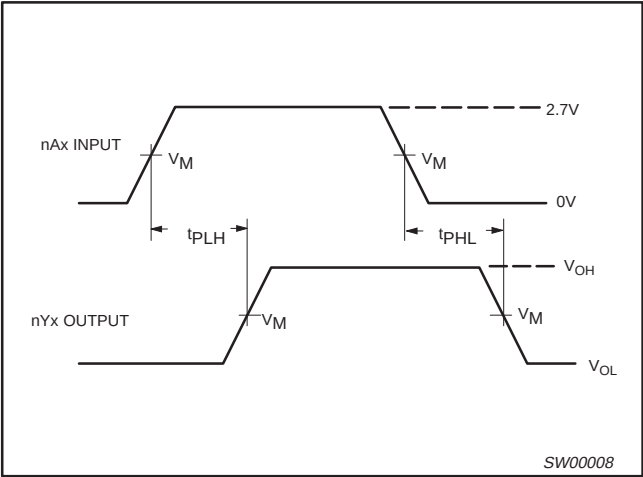
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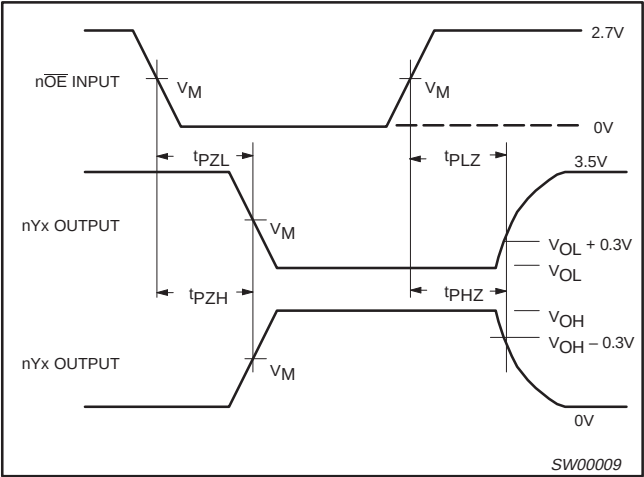
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AC WAVEFORMS

$V_M = 1.5V$, $V_{IN} = GND$ to $3.0V$

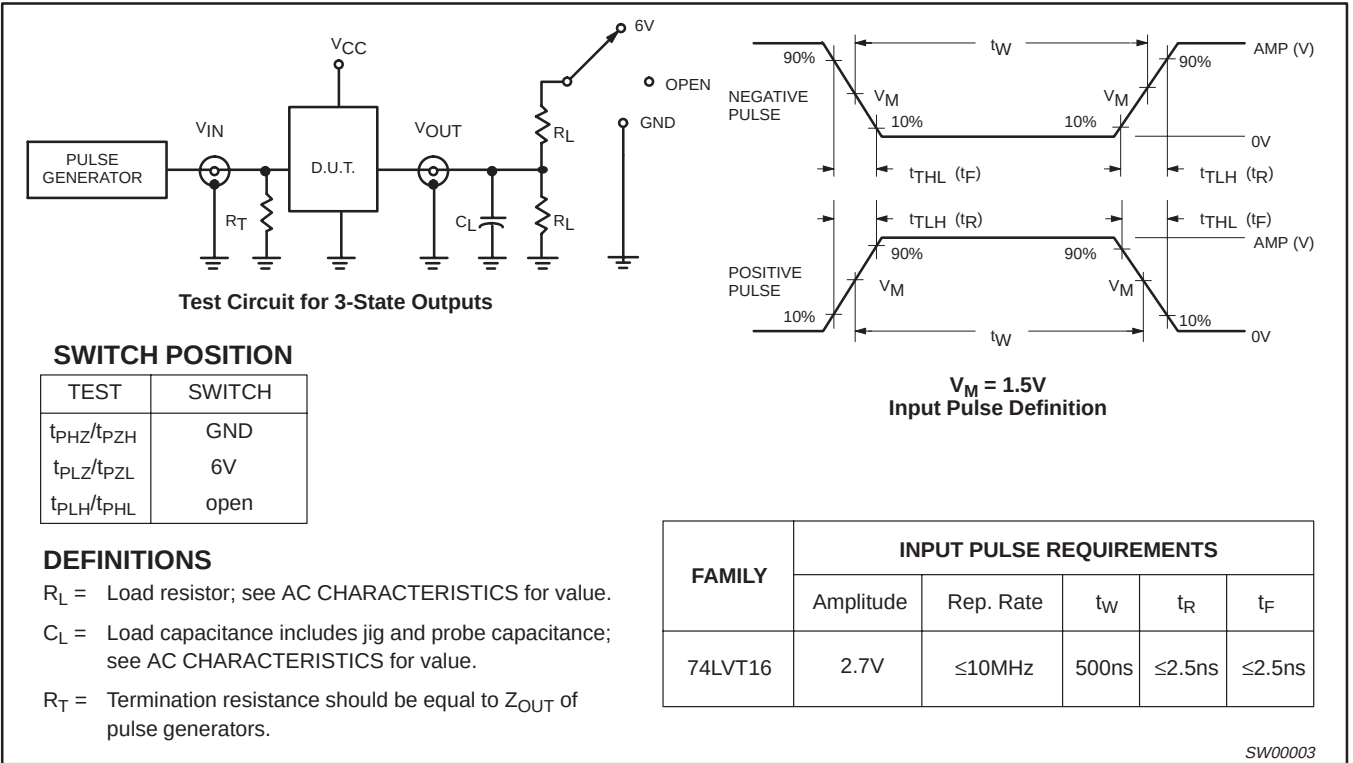


Waveform 1. Input (nAx) to Output (nYx) Propagation Delays



Waveform 2. 3-State Output Enable and Disable Times

TEST CIRCUIT AND WAVEFORMS



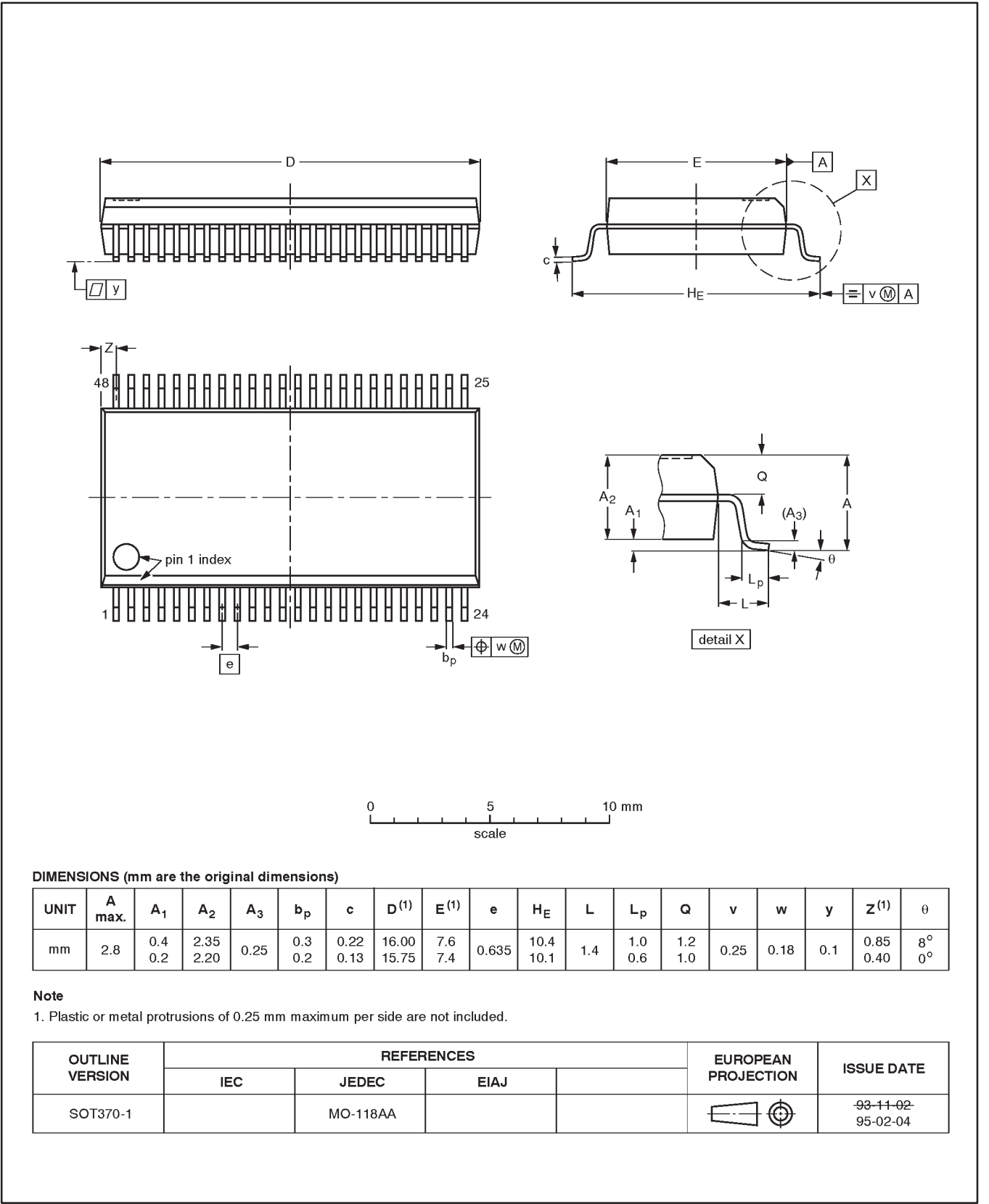
SW00003

3.3V LVT 16-bit buffer/driver (3-State)

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SSOP48: plastic shrink small outline package; 48 leads; body width 7.5 mm

SOT370-1

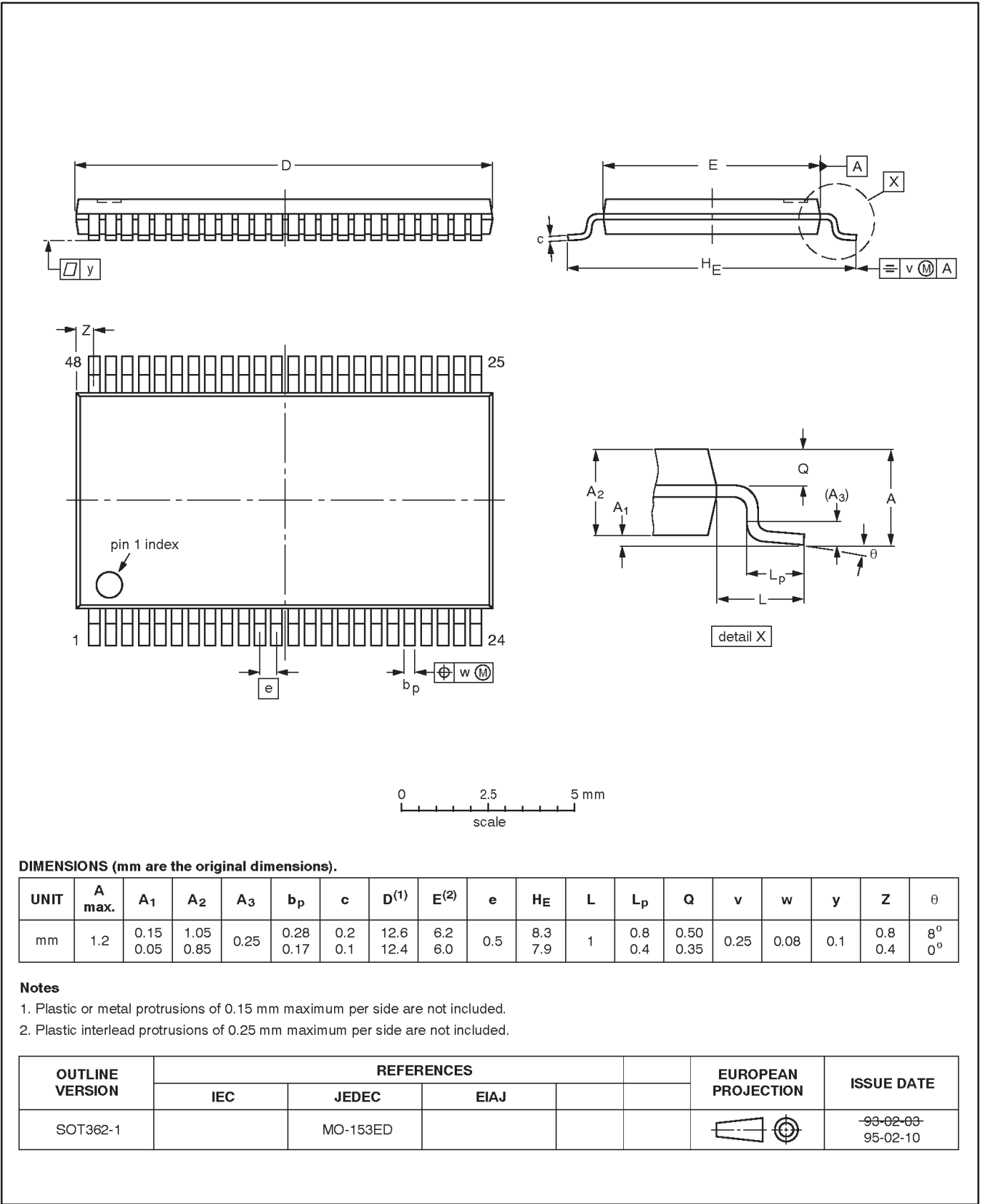


3.3V LVT 16-bit buffer/driver (3-State)

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TSSOP48: plastic thin shrink small outline package; 48 leads; body width 6.1mm

SOT362-1



3.3V LVT 16-bit buffer/driver (3-State)**74LVT16244B**

NOTES

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Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
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[1] Please consult the most recently issued datasheet before initiating or completing a design.

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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Philips Semiconductors
811 East Arques Avenue
P.O. Box 3409
Sunnyvale, California 94088-3409
Telephone 800-234-7381

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